

isc Silicon NPN Power Transistor

DESCRIPTION

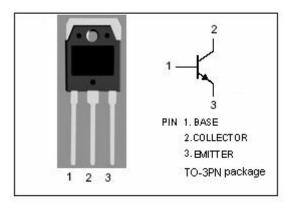
- · High Breakdown Voltage
- · High Switching Speed
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

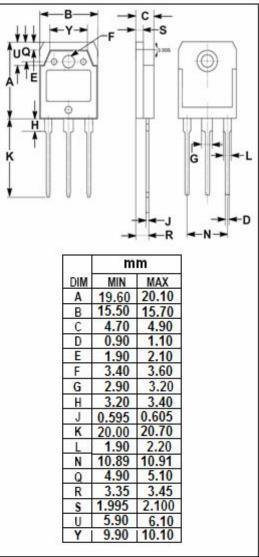
APPLICATIONS

Designed for switching regulator applications.



SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	1100	V	
V _{CEO}	Collector-Emitter Voltage	800	V	
V _{EBO}	Emitter-Base Voltage	7	V	
l _c	Collector Current- Continuous 12		А	
Ісм	Collector Current-Peak	30	A	
l _B	Base Current- Continuous	6	A	
Pc	Pc Collector Power Dissipation @ Tc=25℃		W	
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	°C	







isc Silicon NPN Power Transistor

2SC3552

ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	DADAMETED	CONDITIONS	MINI	TYP.	MAX	UNIT
STIVIDUL	PARAMETER	CONDITIONS	MIN	TTP.	IVIAA	UNII
$V_{(\text{BR})\text{CEO}}$	Collector-Emitter Breakdown Voltage	Ic= 5mA; R _{BE} = ∞	800			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	1100			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 1.2A			2.0	٧
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 6A; I _B = 1.2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V ; I _E = 0			10	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V ; I _C = 0			10	μА
h _{FE-1}	DC Current Gain	I _C = 0.8A; V _{CE} = 5V	10		40	
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 5V	8			
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} =1.0MHz		215		pF
f⊤	Current-Gain—Bandwidth Product	I _C = 0.8A; V _{CE} = 10V		15		MHz
Switching T	imes					
ton	Turn-on Time				0.5	μ s
t _{stg}	Storage Time	I _C = 8A , I _{B1} = 1.6A; I _{B2} = -3.2A R _L = 500 Ω ; V _{CC} =400V			3.0	μ S
t _f	Fall Time				0.3	μs

♦ h_{FE-1} Classifications

K	L	M
10-20	15-30	20-40

Notice:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc website: www.iscsemi.com

² isc & iscsemi is registered trademark